Electronic Supplementary Information

Robust and Transparent Membrane of Crystalline Silicone via Melt-Drawing Technique

Hiroki Uehara,^{*a} Tomohiro Obana,^a Masaki Kakiage,^{a,b} Hidekazu Tanaka,^a Hiroyasu Masunaga,^c Takeshi Yamanobe,^a and Eiichi Akiyama^{*d}

^aDivision of Molecular Science, Faculty of Science and Technology, Gunma University, Kiryu, Gunma 376-8515, Japan; E-mail: hirokiuehara@gunma-u.ac.jp ^bPresent address: Department of Applied Chemistry, Saitama University, 255 Shimo-Okubo, Sakura-ku, Saitama 338-8570, Japan ^cJapan Synchrotron Radiation Research Institute, Sayo, Hyogo 679-5198, Japan

^dSagami Chemical Research Institute, 2743-1 Hayakawa, Ayase, Kanagawa 252-1193, Japan; E-mail: akiyama@sagami.or.jp



Fig S1. An enlarged WAXD pattern for the membrane roll-drawn at 140°C with the reflection indexes. Roll-drawing direction is vertical.



Fig S2 DSC curves for the membranes roll-drawn at 120°C (A), 140°C (B) and 160°C (C). The heating rate was 2°C/min.



Fig S3 DSC curves for the un-drawn SGC film annealed at 120°C (A), 130°C (B), 140°C (C), 150°C (D) and 160°C (E). Heating rate was 10°C/min.